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|----------------------------------|---|
| 2N1038, 2N1039*, 2N1040, 2N1041* | A |
| 2N2552, 2N2553*, 2N2554, 2N2555* | B |
| 2N2556, 2N2557*, 2N2558, 2N2559* | C |

*Available to Military Specifications

PNP GERMANIUM ALLOY JUNCTION POWER TRANSISTORS

These hermetically sealed and dynamically tested units are designed to switch reactive and resistive loads at maximum efficiency by using a unique internal heat-sink design. Each unit can dissipate up to .4 watt in free air at 25°C and up to 1 watt in forced air at 25°C and can also be pressed into suitable heat-sink wells to dissipate up to 8 watts at 71°C. Typical applications include relay drivers, pulse amplifiers, audio amplifiers and high current switching circuits. The collector lead is internally connected to the case.

MAXIMUM DESIGN LIMITS

| | 2N1038 2N2552 2N2556 | 2N1039 2N2553 2N2557 | 2N1040 2N2554 2N2558 | 2N1041 2N2555 2N2559 | Units |
|--|----------------------------|----------------------------|----------------------------|----------------------------|-------|
| Collector-to-Base Voltage, V_{CB} | -40 | -60 | -80 | -100 | Volts |
| Collector-to-Emitter Voltage, V_{CE} | | | | | |
| Acting Region Emitter Forward Biased | -30 | -40 | -50 | -60 | Volts |
| Cutoff Region Emitter Reverse Biased | -40 | -60 | -80 | -100 | Volts |
| Emitter-to-Base Voltage, V_{EB} | | -20 | | | Volts |
| Collector Current, I_C | | -3.0 | | | Amp |
| Base Current, I_B | | -1.0 | | | Amp |
| Operating and Junction Temp. T_J | | -55 to +100 | | | °C |
| Thermal Resistance, Junction to Free Air θ_{JA} | | 185 | | | °C/W |
| Thermal Resistance, Junction to Case θ_{JC} | | 3.67 | | | °C/W |

CHARACTERISTICS AT 25°C CASE TEMPERATURE

| Parameter | Symbol | Condition | Min. | Max. | Units |
|---------------------------------------|--|---|---------------------------|-------|---------------|
| Current Gain, Common Emitter | H_{FE1} | $V_{CE} = -0.5V, I_C = -1A$ | 20 | 60 | — |
| Current Gain, Common Emitter | H_{FE2} | $V_{CE} = -0.5V, I_C = -50mA$ | 33 | 200 | — |
| Base-to-Emitter Voltage | V_{BE1} Y_{FE1} | $V_{CE} = -0.5V, I_C = -1.0A$ | 1.0 | -1.0 | Volts mhos |
| Base-to-Emitter Voltage | V_{BE2} Y_{FE2} | $V_{CE} = -0.5V, I_C = -50mA$ | 0.143 | -0.35 | Volts mhos |
| Collector-Emitter Saturation Voltage* | $V_{CE(sat)}$ | $I_C = -1A, I_B = -100\mu A$ | | 0.25 | Volts |
| Collector Junction Leakage Current | I_{CBO} | | | | |
| | 2N1038, 2N2552, 2N2556 2N1039, 2N2553, 2N2557 2N1040, 2N2554, 2N2558 2N1041, 2N2555, 2N2559 | $V_{CB} = -20V$ $V_{CB} = -30V$ $V_{CB} = -40V$ $V_{CB} = -50V$ | | -125 | μAmp |
| Collector-Base Breakdown Voltage | BV_{CBO} | $I_C = -750$ | | | |
| | 2N1038, 2N2552, 2N2556 2N1039, 2N2553, 2N2557 2N1040, 2N2554, 2N2558 2N1041, 2N2555, 2N2559 | | -40 -60 -80 -100 | | Volts |
| Collector Cutoff Current | I_{CEX} | $V_{BE} = +0.2V$ $V_{CE} = -40V$ $V_{CE} = -60V$ $V_{CE} = -80V$ $V_{CE} = -100V$ | | -650 | μAmp |

*Note: Measured adjacent to header to minimize lead effects.